Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOS III)

# SSM3K15AFU

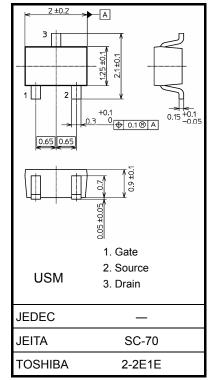
# Load Switching Applications

- 2.5 V drive
- Low ON-resistance:  $R_{DS(ON)} = 3.6 \Omega \text{ (max)} (@V_{GS} = 4 \text{ V})$  $R_{DS(ON)} = 6.0 \Omega \text{ (max)} (@V_{GS} = 2.5 \text{ V})$

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V <sub>DSS</sub>	30	V	
Gate-Source voltage		V <sub>GSS</sub>	$\pm20$	V	
Drain current	DC	I <sub>D</sub>	100	mA	
	Pulse	I <sub>DP</sub>	400		
Power dissipation		P <sub>D</sub> (Note 1)	150	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	–55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

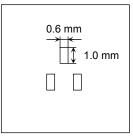


Weight: 6.0 mg (typ.)

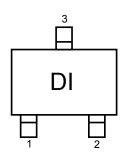
Please design the appropriate reliability upon reviewing the

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

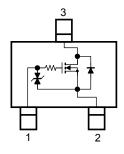
Note 1: Mounted on FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  1.6mm , Cu Pad : 0.6mm<sup>2</sup>  $\times$  3)



## Marking



## Equivalent Circuit (top view)



Start of commercial production 2012-08

Electrical characteristics (Ta = 25°C)

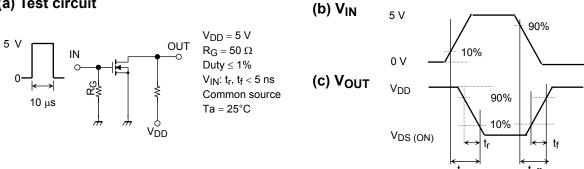
Chara	icteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V
		V (BR) DSX	$I_D = 0.1 \text{ mA}, V_{GS} = -10 \text{ V}$ (Note 3)	16		_	
Drain cut-off currer	it	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±1	μA
Gate threshold volt	age	V <sub>th</sub>	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.8		1.5	V
Forward transfer a	dmittance	Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}$ (Note 2)	35		_	mS
Drain-Source ON-resistance		R <sub>DS (ON)</sub>	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note 2)		2.3	3.6	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note 2)		3.5	6.0	
Input capacitance		C <sub>iss</sub>			13.5	_	pF
Output capacitance		C <sub>oss</sub>	$V_{DS} = 3 V, V_{GS} = 0 V, f = 1 MHz$		8.0		
Reverse transfer capacitance		C <sub>rss</sub>			6.5	_	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 5 \text{ V}, \text{ I}_{D} = 10 \text{ mA}$ $V_{GS} = 0 \text{ to } 5 \text{ V}, \text{ R}_{G} = 50 \Omega$		5.5	_	ns
	Turn-off time	t <sub>off</sub>			35	_	
Drain-source forward voltage		V <sub>DSF</sub>	$I_D = -100 \text{ mA}, V_{GS} = 0 \text{ V}$ (Note 2)		-0.85	-1.2	V

Note 2: Pulse test

Note 3: If a reverse bias is applied between gate and source, this device enters V(BR)DSX mode. Note that the drain-source breakdown voltage is lowered in this mode

# Switching Time Test Circuit

(a) Test circuit



#### Precaution

Vth can be expressed as voltage between gate and source when low operating current value is ID = 0.1 mA for this product. For normal switching operation, V<sub>GS</sub> (on) requires higher voltage than V<sub>th</sub> and V<sub>GS</sub> (off) requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS (off)} < V_{th} < V_{GS (on)}$ )

Please take this into consideration for using the device.

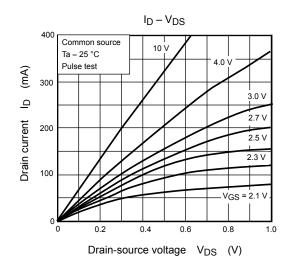
Do not use this device under avalanche mode. It may cause the device to break down.

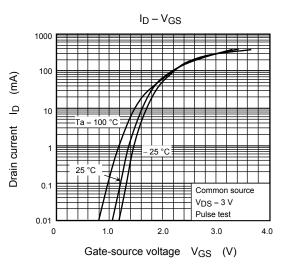
## **Handling Precaution**

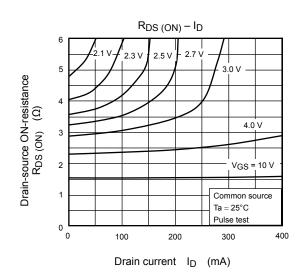
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

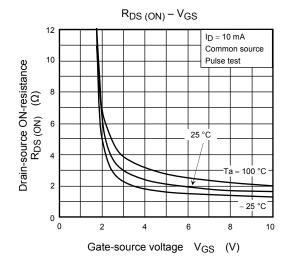
Thermal resistance Rth (ch-a) and power dissipation PD vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

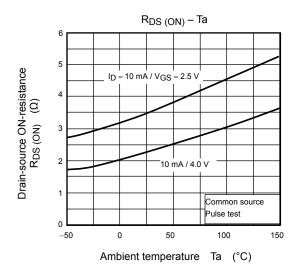
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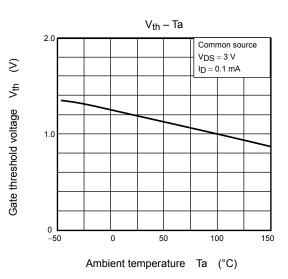




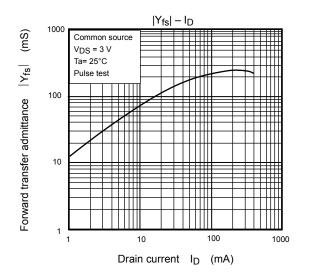


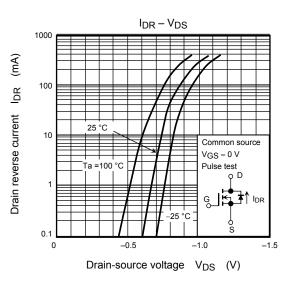


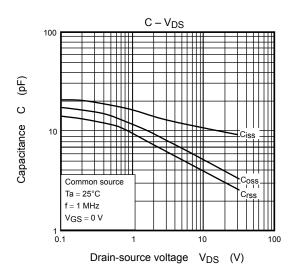


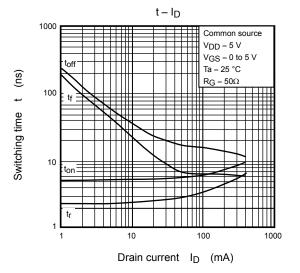


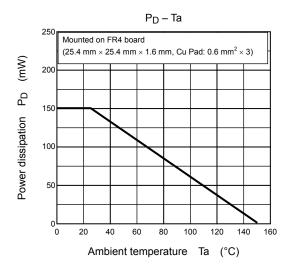
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